AUIRFR5505

International **TOR** Rectifier

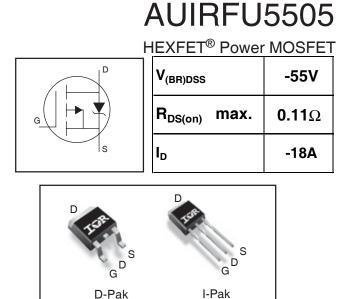
AUTOMOTIVE GRADE

Features

- Advanced Planar Technology
- Low On-Resistance
- P-Channel
- Dynamic dV/dT Rating
- 150°C Operating Temperature
- Fast Switching
- Fully Avalanche Rated
- Repetitive Avalanche Allowed up to Tjmax
- Lead-Free, RoHS Compliant
- Automotive Qualified *

Description

Specifically designed for Automotive applications, this Cellular design of HEXFET® Power MOSFETs utilizes the latest processing techniques to achieve low onresistance per silicon area. This benefit combined with the fast switching speed and ruggedized device design that HEXFET power MOSFETs are well known for, provides the designer with an extremely efficient and reliable device for use in Automotive and a wide variety of other applications.



| AUIRF | R5505 AUIF | RFU5505 |
|-------|------------|---------|
| G | D | S |
| Gate | Drain | Source |

Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature (T_A) is 25°C, unless otherwise specified.

| | Parameter | Max. | Units |
|---|--|------------------------|-------|
| I _D @ T _C = 25°C | Continuous Drain Current, V _{GS} @ -10V | -18 | |
| I _D @ T _C = 100°C | Continuous Drain Current, V _{GS} @ -10V | -11 | А |
| IDM | Pulsed Drain Current ① | -64 | |
| P _D @T _C = 25°C | Power Dissipation | 57 | W |
| | Linear Derating Factor | 0.45 | W/°C |
| V _{GS} | Gate-to-Source Voltage | ± 20 | V |
| E _{AS} | Single Pulse Avalanche Energy(Thermally limited) 2 | 150 | mJ |
| I _{AR} | Avalanche Current ① | -9.6 | А |
| E _{AR} | Repetitive Avalanche Energy ① | 5.7 | mJ |
| dv/dt | Peak Diode Recovery dv/dt ③ | -5.0 | V/ns |
| TJ | Operating Junction and | -55 to + 150 | |
| T _{STG} | Storage Temperature Range | | °C |
| | Soldering Temperature, for 10 seconds | 300 (1.6mm from case) | |

Thermal Resistance

| | Parameter | Тур. | Max. | Units |
|------------------|------------------------------------|------|------|-------|
| R _{eJC} | Junction-to-Case | | 2.2 | |
| R _{eJA} | Junction-to-Ambient (PCB mount) ** | | 50 | °C/W |
| R _{0JA} | Junction-to-Ambient | | 110 | |

HEXFET[®] is a registered trademark of International Rectifier. *Qualification standards can be found at http://www.irf.com/

Static Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

| | Parameter | Min. | Тур. | Max. | Units | Conditions |
|-----------------------------------|--------------------------------------|------|--------|------|-------|--|
| V _{(BR)DSS} | Drain-to-Source Breakdown Voltage | -55 | | | V | $V_{GS} = 0V, I_{D} = -250\mu A$ |
| $\Delta V_{(BR)DSS} / \Delta T_J$ | Breakdown Voltage Temp. Coefficient | | -0.049 | | V/°C | Reference to 25° C, I _D = -1mA |
| R _{DS(on)} | Static Drain-to-Source On-Resistance | | | 0.11 | Ω | $V_{GS} = -10V, I_{D} = -9.6A$ (4) |
| V _{GS(th)} | Gate Threshold Voltage | -2.0 | | -4.0 | V | $V_{DS} = V_{GS}, I_D = -250 \mu A$ |
| gfs | Forward Transconductance | 4.2 | | | S | V _{DS} = -25V, I _D = -9.6A ⑥ |
| I _{DSS} | Drain-to-Source Leakage Current | | | -25 | μA | $V_{DS} = -55V, V_{GS} = 0V$ |
| | | | | -250 | | $V_{DS} = -44V, V_{GS} = 0V, T_{J} = 150^{\circ}C$ |
| I _{GSS} | Gate-to-Source Forward Leakage | | | 100 | nA | $V_{GS} = -20V$ |
| | Gate-to-Source Reverse Leakage | | | -100 | | V _{GS} = 20V |

Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

| Q _g | Total Gate Charge | | | 32 | | I _D = -9.6A |
|---------------------|---------------------------------|---|-----|-----|----|--|
| Q _{gs} | Gate-to-Source Charge | | | 7.1 | nC | $V_{DS} = -44V$ |
| Q _{gd} | Gate-to-Drain ("Miller") Charge | | | 15 | | V_{GS} = -10V,See Fig 6 and 13 $\textcircled{4}$ |
| t _{d(on)} | Turn-On Delay Time | | 12 | | | $V_{DD} = -28V$ |
| t _r | Rise Time | | 28 | | | I _D = -9.6A |
| t _{d(off)} | Turn-Off Delay Time | | 20 | | ns | $R_G = 2.6 \Omega$ |
| t _f | Fall Time | | 16 | | | $R_D = 2.8\Omega$, See Fig.10 ④ |
| L _D | Internal Drain Inductance | | 4.5 | | nH | Between lead, 6mm (0.25in.) |
| L _S | Internal Source Inductance | _ | 7.5 | | | from package |
| C _{iss} | Input Capacitance | | 650 | | | $V_{GS} = 0V$ |
| C _{oss} | Output Capacitance | | 270 | | pF | V _{DS} = -25V |
| C _{rss} | Reverse Transfer Capacitance | | 120 | | | f = 1.0MHz,see Fig.5 |

Diode Characteristics

| | Parameter | Min. | Тур. | Max. | Units | Conditions | | | | |
|-----------------|---------------------------|-----------|--|------|-------|---|-----|-----|--|------------------|
| I _S | Continuous Source Current | | | -18 | | MOSFET symbol | | | | |
| | (Body Diode) | | | | | showing the | | | | |
| I _{SM} | Pulsed Source Current | | | 64 | 64 | 64 | -64 | -64 | | integral reverse |
| | (Body Diode) ① | | | -04 | | p-n junction diode. | | | | |
| V _{SD} | Diode Forward Voltage | | | -1.6 | V | $T_{J} = 25^{\circ}C, I_{S} = -9.6A, V_{GS} = 0V$ (4) | | | | |
| t _{rr} | Reverse Recovery Time | | 51 | 77 | ns | T _J = 25°C, I _F = -9.6A | | | | |
| Q _{rr} | Reverse Recovery Charge | | 110 | 160 | nC | di/dt = 100A/µs ④ | | | | |
| t _{on} | Forward Turn-On Time | Intrinsic | Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD) | | | | | | | |

Notes:

- ① Repetitive rating; pulse width limited by max. junction temperature. (See fig. 11).
- $\$ Starting T_J = 25°C, L = 2.8mH
- $R_G = 25\Omega$, $I_{AS} = -6.6A$ (See Figure 12)
- $(\textbf{3} | I_{SD} \leq \textbf{-6.6A}, \, di/dt \leq \textbf{-240A}/\mu \textbf{s}, \, V_{DD} \leq V_{(BR)DSS}, \\$

T_J ≤ 150°C

(Pulse width \leq 300µs; duty cycle \leq 2%.

- $\ensuremath{\textcircled{\text{S}}}$ This is applied for I-PAK, L_S of D-PAK is measured between lead and center of die contact.
- © Uses IRF9Z24N data and test conditions.

** When mounted on 1" square PCB (FR-4 or G-10 Material). For recommended footprint and soldering techniques refer to application note #AN-994.

Qualification Information[†]

| | | Automotive | | | | |
|----------------------------|----------------------------|------------------------------|--|--|--|--|
| | | (per AEC-Q101) ^{††} | | | | |
| Qualification Lev | vel | qualification. | This part number(s) passed Automotive IR's Industrial and Consumer qualification ed by extension of the higher Automotive level. | | | |
| Majatura Sanaitivity Laval | | D PAK | MSL1 | | | |
| Moisture Serisiti | Moisture Sensitivity Level | | N/A | | | |
| | Machine Model | Class M3 (250V) | | | | |
| | | (per AEC-Q101-002) | | | | |
| 500 | Human Body Model | Class H1B (800V) | | | | |
| ESD | | | (per AEC-Q101-001) | | | |
| | Charged Device | Class C5 (2000V) | | | | |
| Model | | (per AEC-Q101-005) | | | | |
| RoHS Compliant | ! | Yes | | | | |

† Qualification standards can be found at International Rectifier's web site: http://www.irf.com/

†† Exceptions to AEC-Q101 requirements are noted in the qualification report.

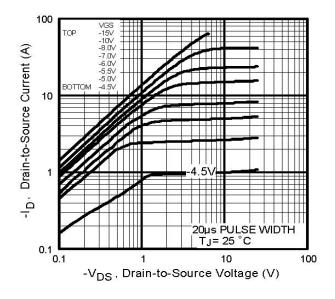


Fig 1. Typical Output Characteristics

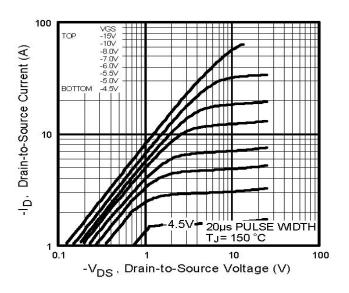


Fig 2. Typical Output Characteristics

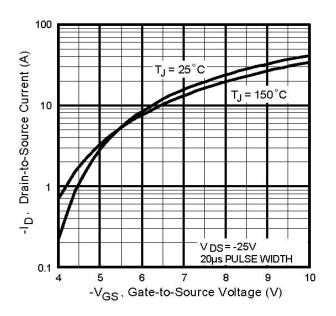
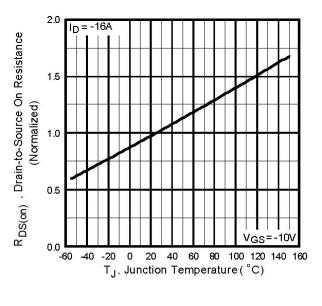
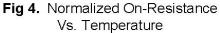


Fig 3. Typical Transfer Characteristics





International **IOR** Rectifier

AUIRFR/U5505

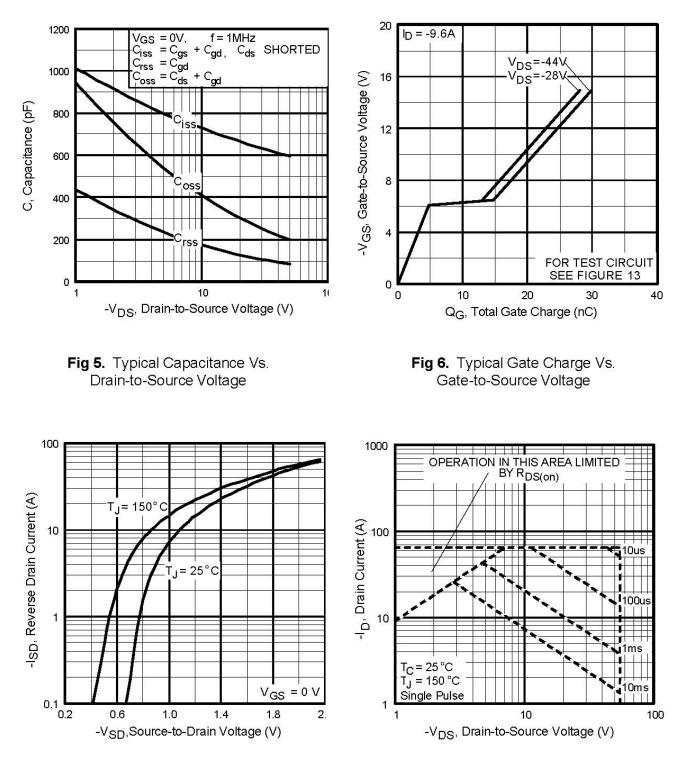
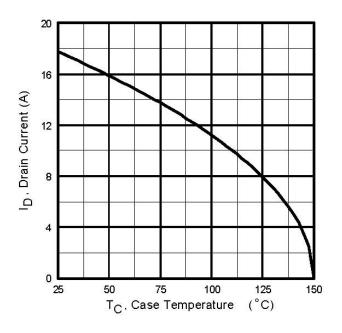
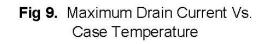


Fig 7. Typical Source-Drain Diode Forward Voltage

Fig 8. Maximum Safe Operating Area





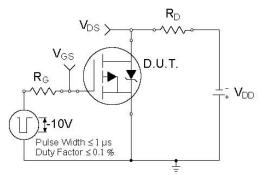


Fig 10a. Switching Time Test Circuit

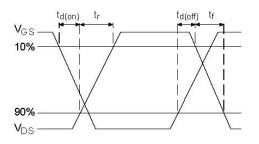


Fig 10b. Switching Time Waveforms

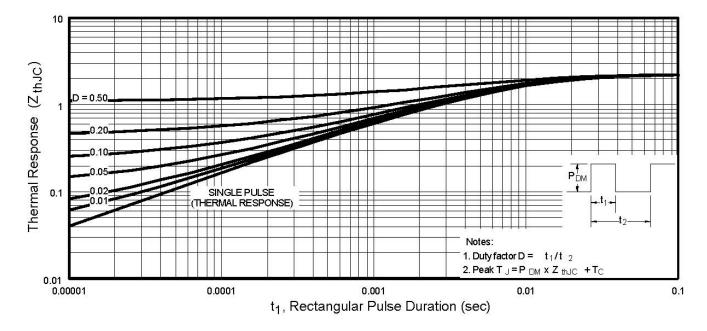
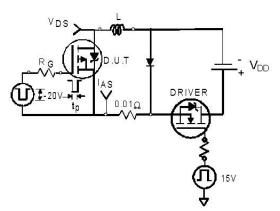
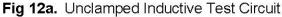


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case





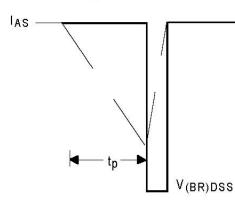
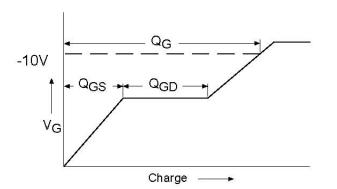
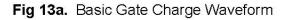
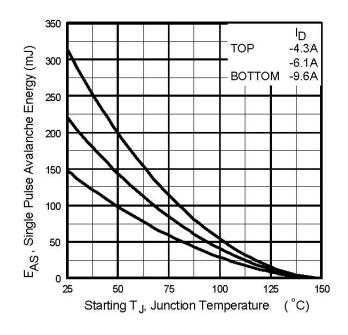
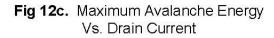


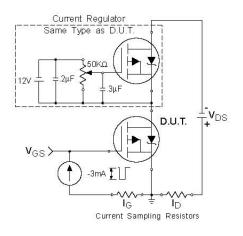
Fig 12b. Unclamped Inductive Waveforms



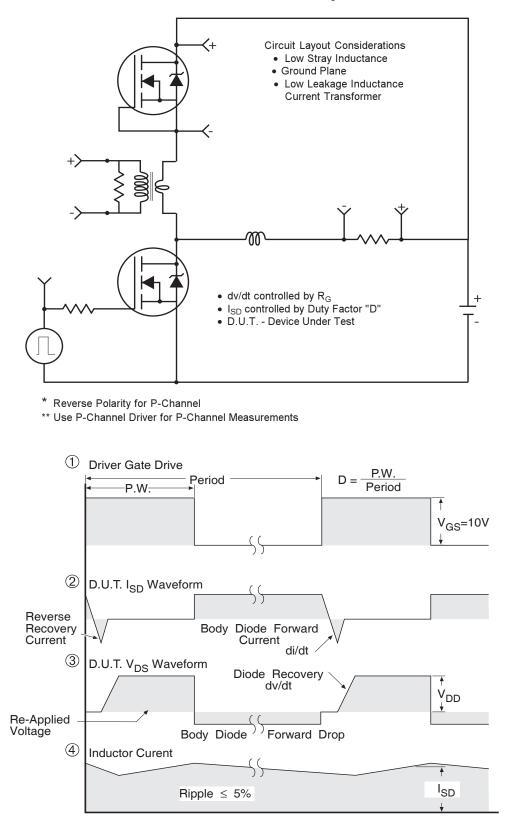










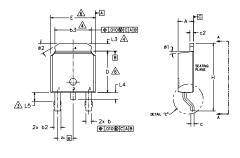


Peak Diode Recovery dv/dt Test Circuit

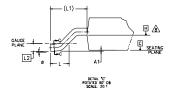
*** $V_{\rm GS}$ = 5.0V for Logic Level and 3V Drive Devices

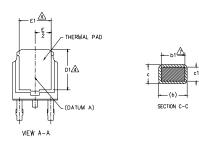
D-Pak (TO-252AA) Package Outline

Dimensions are shown in millimeters (inches)







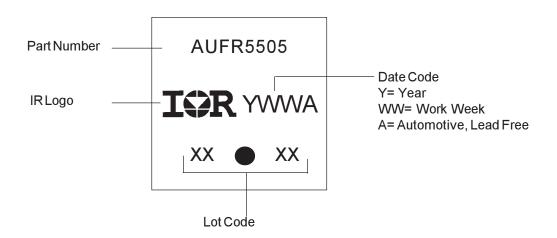


| ı٨ | ΤС | c. | |
|----|----|----|--|

- 1.- DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
- 2.- DIMENSION ARE SHOWN IN INCHES [MILLIMETERS]
- A- LEAD DIMENSION UNCONTROLLED IN L5.
- A- DIMENSION D1, E1, L3 & 63 ESTABLISH A MINIMUM MOUNTING SURFACE FOR THERMAL PAD. - SECTION C-C DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .005 AND 0.10 [0.13 AND 0.25] FROM THE LEAD TIP. 5,-
- 6.-DIMENSION D & E DO NOT INCLUDE MOLD FLASH, MOLD FLASH SHALL NOT EXCEED .005 [0.13] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
- A- DIMENSION 61 & c1 APPLIED TO BASE METAL ONLY.
- A- DATUM A & B TO BE DETERMINED AT DATUM PLANE H.
- 9.- OUTLINE CONFORMS TO JEDEC OUTLINE TO-252AA.

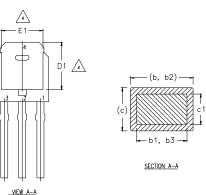
| SY | | | SIONS | | N | |
|--------|--------|-------|-------|------|--------|---------------------|
| в | MILLIM | ETERS | INC | HES | 0 T | |
| 0 L | Min. | MAX. | MIN. | MAX. | E S | |
| Α | 2.18 | 2.39 | .086 | .094 | | |
| A1 | - | 0.13 | - | .005 | | |
| b | 0.64 | 0.89 | .025 | .035 | | |
| ь1 | 0,65 | 0,79 | .025 | .031 | 7 | |
| b2 | 0.76 | 1.14 | .030 | .045 | | |
| b3 | 4,95 | 5,46 | .195 | .215 | 4 | |
| с | 0.46 | 0.61 | .018 | .024 | | |
| c1 | 0.41 | 0.56 | .016 | .022 | 7 | |
| c2 | 0.46 | 0.89 | .018 | .035 | | |
| D | 5.97 | 6.22 | .235 | .245 | 6 | LEAD ASSIGNMENTS |
| D1 | 5.21 | - | .205 | - | 4 | |
| Е | 6,35 | 6.73 | .250 | .265 | 6 | HEXFET |
| E1 | 4.32 | - | .170 | - | 4 | <u>HEATE1</u> |
| е | 2.29 | BSC | .090 | BSC | | 1 GATE |
| н | 9.40 | 10.41 | .370 | .410 | | 2 DRAIN |
| L | 1.40 | 1.78 | .055 | .070 | | 3 SOURCE 4 DRAIN |
| L1 | 2.74 | BSC | .108 | REF. | 1 | 4 DRAIN |
| L2 | 0.51 | BSC | .020 | BSC | | |
| L3 | 0.89 | 1.27 | .035 | .050 | 4 | IGBT & CoPAK |
| L4 | - | 1.02 | - | .040 | | IGBT & COFAR |
| L5 | 1.14 | 1.52 | .045 | .060 | 3 | 1 GATE |
| ø | 0* | 10* | 0* | 10* | | 2 COLLECTOR |
| ø1 | 0* | 15* | 0* | 15* | | 3 EMITTER |
| ø2 | 25' | 35* | 25' | 35* | | 4 COLLECTOR |
| | | | | | | |

D-Pak (TO-252AA) Part Marking Information



I-Pak (TO-251AA) Package Outline (Dimensions are shown in millimeters (inches)

- A ⊕ 0.010 (0.025) (0 C A B -8 С SEATING 11 ь2 3× 5 3х A1 Ċ ⊕ 0.010 (0.25) ⊕ C A B e



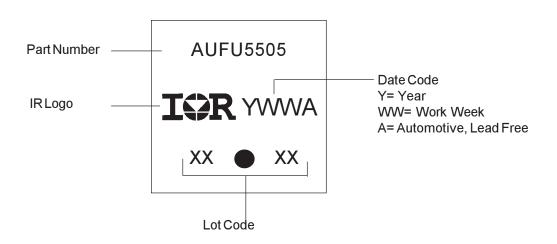
NOTES:

- 1 DIMENSIONING AND TOLERANCING PER ASME Y14.5 M- 1994. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES],
- DMENSION D & E DO NOT INCLUDE WOLD FLASH, MOLD FLASH SHALL NOT EXCEED 0.005" (0.127) PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY. 3
- THERMAL PAD CONTOUR OPTION WITHIN DIMENSION 64, L2, E1 & D1.
- LEAD DIMENSION UNCONTROLLED IN L3.
- 6 DIMENSION 61, 63 APPLY TO BASE METAL ONLY.
- OUTLINE CONFORMS TO JEDEC OUTLINE TO-251AA. CONTROLLING DIMENSION : INCHES. 8

LEAD ASSIGNMENTS

DIMENSIONS HEXFET SYMBOL MILLIMETERS INCHES NOTES MIN. MAX. MIN. MAX. 1.- GATE 2.- DRAIN 3.- SOURCE 2.18 0.086 .094 2.39 A1 0,89 1,14 0.035 0,045 4,- DRAIN b 0.64 0.89 0.025 0.035 ь1 0.64 0,79 0.025 0.031 4 b2 0.76 1,14 0.030 0.045 b3 0.76 1.04 0.030 0.041 b4 5.00 5.46 0.195 0.215 4 0.61 0.46 0.018 0.024 с cſ 0.41 0,56 0,016 0.022 c2 .046 0.86 0.018 0.035 D 5.97 6.22 0.235 0.245 3, 4 D1 5.21 0,205 4 6.73 Ε 6.35 0.250 0.265 3, 4 E1 4,32 0,170 4 e 0.09 BSC 9.60 L 8,89 0.350 0,380 L1 1,91 2.29 0.075 0.090 L2 0,89 1.27 0.035 0.050 L3 1,14 1.52 0.045 0,060 5 ø1 0* 15' 0" 15'

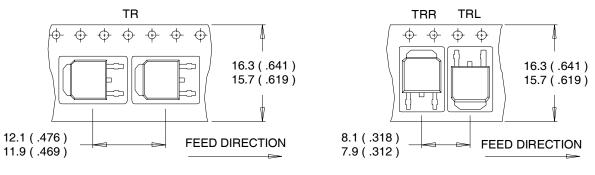
I-Pak (TO-251AA) Part Marking Information



Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

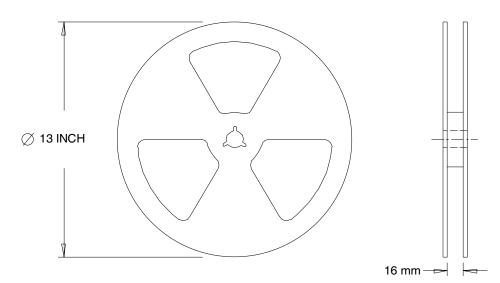
D-Pak (TO-252AA) Tape & Reel Information

Dimensions are shown in millimeters (inches)



NOTES :

- 1. CONTROLLING DIMENSION : MILLIMETER.
- 2. ALL DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).
- 3. OUTLINE CONFORMS TO EIA-481 & EIA-541.



NOTES :

1. OUTLINE CONFORMS TO EIA-481.

Ordering Information

| Base part | Package Type | Standard Pac | k | Complete Part Number |
|------------|--------------|---------------------|----------|----------------------|
| | | Form | Quantity | |
| AUIRFR5505 | DPak | Tube | 75 | AUIRFR5505 |
| | | Tape and Reel | 2000 | AUIRFR5505TR |
| | | Tape and Reel Left | 3000 | AUIRFR5505TRL |
| | | Tape and Reel Right | 3000 | AUIRFR5505TRR |
| AUIRFU5505 | IPak | Tube | 75 | AUIRFU5505 |

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